

RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

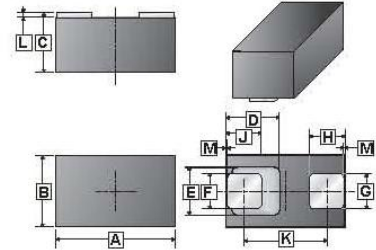
DESCRIPTION

The STESD05C is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space is at a premium.

FEATURES

- Stand-off voltage: 5V
- Low Leakage
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (>16kV) per Human Body Model
- IEC61000-4-2 Level 4 ESD Protection
- IEC61000-4-4 Level 4 EFT Protection
- These are Pb-Free Devices

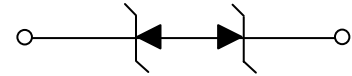
WBFBP-02C



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	0.950	1.050	G	0.275	0.325
B	0.550	0.650	H	0.275	0.325
C	0.450	0.550	J	0.275	0.325
D	0.450 REF.		K	0.675	0.725
E	0.400 REF.		L	0.010	0.070
F	0.275	0.325	M	0.010 REF.	

PACKAGE INFORMATION

Package	MPQ	Leader Size
WBFBP-02C	10K	7" inch



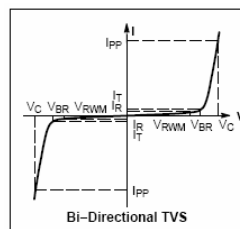
DEVICE MARKING: EB

MAXIMUM RATINGS (T_A = 25°C)

PARAMETER		SYMBOL	VALUE	UNIT
IEC 61000-4-2 (ESD)	Air		±30	KV
	Contact		±30	
ESD voltage	Per Human Body Model		16	KV
	Per Machine Model		400	
Total power dissipation on FR-5 Board (Note 1)		P _D	100	mW
Thermal Resistance Junction-to-Ambient		R _{θJA}	1250	°C / W
Junction and Storage Temperature Range		T _J , T _{STG}	-55 ~ +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)		T _L	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended. Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = 1.0 x 0.75 x 0.62 in.



ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Working Peak Reverse Voltage	V_{RWM}	-	-	5.0	V
Maximum Reverse Leakage Current @ V_{RWM}	I_R	-	-	1.0	μA
Breakdown Voltage @ I_T (Note2)	V_{BR}	5.8	-	8.8	V
Test Current	I_T	-	-	1.0	mA
Maximum Reverse Peak Pulse Current (Note3)	I_{PP}	-	-	11.2	A
Clamping Voltage @ I_{PP} (Note3)	V_C	-	-	12.5	V
Max. Capacitance @ $V_R = 0$ and $f = 1\text{MHz}$	C	-	-	30	pF

2. V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C .
3. Test by $T_p = 8 / 20 \mu\text{s}$ pulse waveform.